



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Appl. No.	10/771,593	Confirmation No.	3820
First Inventor	Hamza Yilmaz	Filing Date	February 2, 2004
Tech. Center/ Art Unit	2826	Examiner	Fetsum Abraham
Title:	Semiconductor Device Containing Dielectrically Isolated PN Junction For Enhanced Breakdown Characteristics		
Docket No.:	YMZ004 US	Customer No.:	34036

Santa Clara, California
April 26, 2005

Mail Stop Issue Fee
COMMISSIONER FOR PATENTS
P.O. Box 1450
Alexandria, VA 22313-1450

AMENDMENT PURSUANT TO 37 CFR 1.312

Dear Sir:

Pursuant to 37 CFR 1.312, please amend the above-identified application as follows.

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims are reflected in the listing of claims which begins on page 4 of this paper.

Remarks/Arguments begin on page 6 of this paper.